

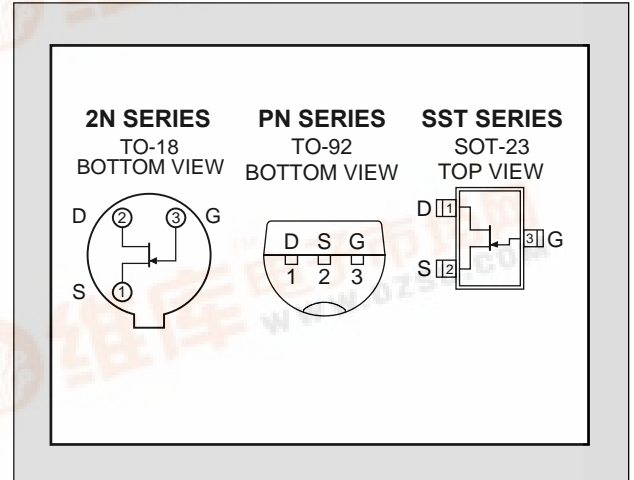
LINEAR SYSTEMS

Linear Integrated Systems

2N/PN/SST4391 SERIES

SINGLE N-CHANNEL JFET SWITCH

FEATURES	
Replacement for Siliconix 2N/PN/SST4391, 4292, & 4393	
LOW ON RESISTANCE	$r_{DS(on)} \leq 30\Omega$
FAST SWITCHING	$t_{ON} \leq 15ns$
ABSOLUTE MAXIMUM RATINGS ¹	
@ 25 °C (unless otherwise stated)	
Maximum Temperatures	
Storage Temperature (2N)	-65 to 200°C
Storage Temperature (PN/SST)	-55 to 150°C
Junction Operating Temperature (2N)	-55 to 200°C
Junction Operating Temperature (PN/SST)	-55 to 150°C
Maximum Power Dissipation	
Continuous Power Dissipation (2N)	1800mW
Continuous Power Dissipation (PN/SST)	350mW
Maximum Currents	
Gate Current	50mA
Maximum Voltages	
Gate to Drain or Source (2N/PN)	-40V
Gate to Drain or Source (SST)	-35V



STATIC ELECTRICAL CHARACTERISTICS @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC	TYP	4391		4392		4393		UNIT	CONDITIONS			
			MIN	MAX	MIN	MAX	MIN	MAX					
BV _{GSS}	Gate to Source Breakdown Voltage	2N/PN	-40		-40		-40		V	I _G = -1μA, V _{DS} = 0V			
		SST	-35		-35		-35						
V _{GS(off)}	Gate to Source Cutoff Voltage	2N/PN	-4	-10	-2	-5	-0.5	-3			V	V _{DS} = 20V, I _D = 1nA V _{DS} = 15V, I _D = 10nA	
		SST	-4	-10	-2	-5	-0.5	-3					
V _{GS(F)}	Gate to Source Forward Voltage	0.7		1		1	1	mA					I _G = 1mA, V _{DS} = 0V V _{GS} = 0V, I _D = 3mA V _{GS} = 0V, I _D = 6mA V _{GS} = 0V, I _D = 12mA
V _{DS(on)}	Drain to Source On Voltage	0.25					0.4						
		0.3			0.4								
		0.35	0.4										
I _{DSS}	Drain to Source Saturation Current ²	2N	50	150	25	75	5		30	mA	V _{DS} = 20V, V _{GS} = 0V		
		PN	50	100	25	100	5		60				
		SST	50		25		5						
I _{GSS}	Gate Leakage Current	2N/SST	-5	-100		-100		-100	pA	V _{GS} = -20V, V _{DS} = 0V V _{DG} = 15V, I _D = 10mA			
		PN	-5	-1000		-1000		-1000					
I _G	Gate Operating Current	-5											

STATIC ELECTRICAL CHARACTERISTICS CONT. @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS	
				MIN	MAX	MIN	MAX	MIN	MAX			
I _{D(off)}	Drain Cutoff Current	2N	5						100	pA	V _{DS} = 20V, V _{GS} = -5V	
			5				100				V _{DS} = 20V, V _{GS} = -7V	
			5		100						V _{DS} = 20V, V _{GS} = -12V	
		PN	5						1000			V _{DS} = 20V, V _{GS} = -5V
			5					1000				V _{DS} = 20V, V _{GS} = -7V
			5		1000							V _{DS} = 20V, V _{GS} = -12V
		SST	5		100		100		100			V _{DS} = 10V, V _{GS} = -10V
r _{DS(on)}	Drain to Source On Resistance				30		60		100	Ω	V _{GS} = 0V, I _D = 1mA	

DYNAMIC ELECTRICAL CHARACTERISTICS @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS
				MIN	MAX	MIN	MAX	MIN	MAX		
g _{fs}	Forward Transconductance		6							mS	V _{DS} = 20V, I _D = 1mA f = 1kHz
g _{os}	Output Conductance		25							μS	
r _{DS(on)}	Drain to Source On Resistance				30		60		100	Ω	V _{GS} = 0V, I _D = 0A f = 1kHz
C _{iss}	Input Capacitance	2N	12		14		14		14	pF	V _{DS} = 20V, V _{GS} = 0V f = 1MHz
		PN	12		16		16		16		
		SST	13								
C _{rss}	Reverse Transfer Capacitance	2N	3.3						3.5	pF	V _{DS} = 0V, V _{GS} = -5V f = 1MHz
		PN	3.5						5		
		SST	3.6								
		2N	3.2				3.5			pF	V _{DS} = 0V, V _{GS} = -7V f = 1MHz
		PN	3.4				5				
		SST	3.5								
		2N	2.8		3.5						
PN	3.0		5						pF	V _{DS} = 0V, V _{GS} = -12V f = 1MHz	
SST	3.1										
e _n	Equivalent Input Noise Voltage		3							nV/√Hz	V _{DS} = 10V, I _D = 10mA f = 1kHz

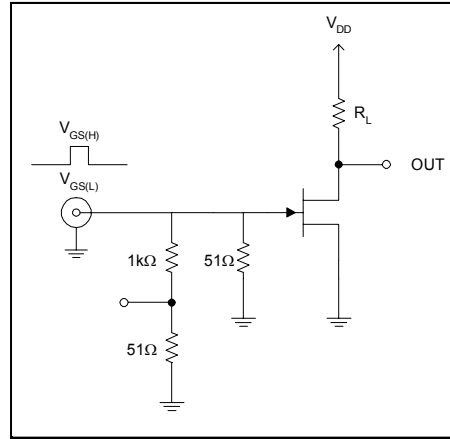
SWITCHING ELECTRICAL CHARACTERISTICS @25 °C (unless otherwise stated)

SYM.	CHARACTERISTIC		TYP	4391		4392		4393		UNIT	CONDITIONS
				MIN	MAX	MIN	MAX	MIN	MAX		
t _{d(on)}	Turn On Time	2N/PN	2		15		15		15	ns	V _{DD} = 10V, V _{GS(H)} = 0V
		SST	2								
t _r		2N/PN	2		5		5		5		
		SST	2								
t _{d(off)}	Turn Off Time	2N/PN	6		20		35		50	ns	V _{DD} = 10V, V _{GS(H)} = 0V
		SST	6								
t _f		2N/PN	13		15		20		30		
		SST	13								

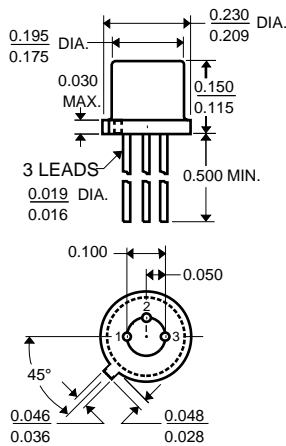
SWITCHING CIRCUIT CHARACTERISTICS

SYM.	4391	4392	4393
$V_{GS(L)}$	-12V	-7V	-5V
R_L	800 Ω	1600 Ω	3200 Ω
$I_{D(on)}$	12mA	6mA	3mA

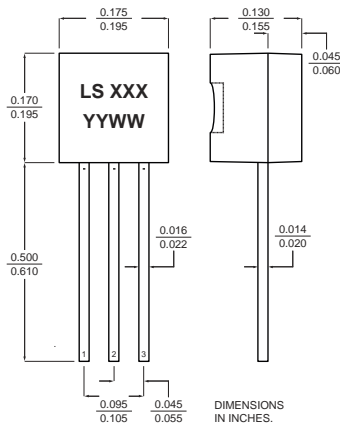
SWITCHING TEST CIRCUIT



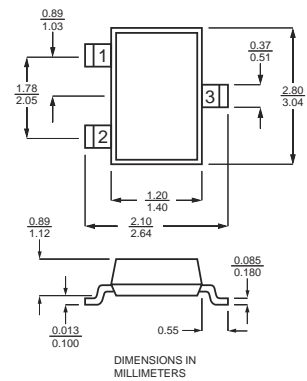
TO-18 Three Lead



TO-92



SOT-23



NOTES

1. Absolute maximum ratings are limiting values above which serviceability may be impaired.
2. Pulse test: $PW \leq 300\mu s$, Duty Cycle $\leq 3\%$

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